

# UNISONIC TECHNOLOGIES CO., LTD

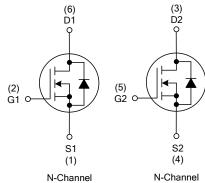
**UP672 Power MOSFET** 

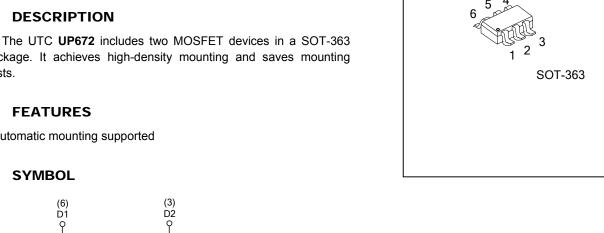
## **N-CHANNEL MOSFET ARRAY** FOR SWITCHING

package. It achieves high-density mounting and saves mounting costs.

#### **FEATURES**

\* Automatic mounting supported

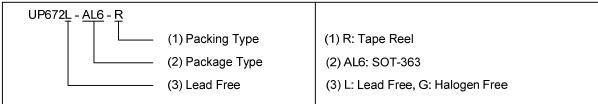




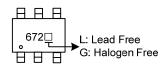
#### ORDERING INFORMATION

Ordering Number		Dealessa	Pin Assignment					Daaliaa		
Lead Free	Halogen Free	Package	1	2	3	4	5	6	Packing	
UP672L-AL6-R	UP672G-AL6-R	SOT-363	S1	G1	D2	S2	G2	D1	Tape Reel	

Note: Pin Assignment: G: Gate D: Drain S: Source



#### **MARKING**



#### ■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		$V_{ extsf{DSS}}$	50	V
Gate-Source Voltage		$V_{GSS}$	±7.0	V
Drain Current	Continuous	I <sub>D</sub>	100	mA
Drain Current	Pulsed (Note 2)	I <sub>DM</sub>	200	mA
Total Power Dissipation		$P_D$	200	mW
Channel Temperature		T <sub>CH</sub>	150	°C
Storage Temperature Range		T <sub>STG</sub>	-55 ~ +150	°C

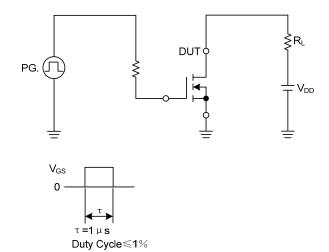
Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

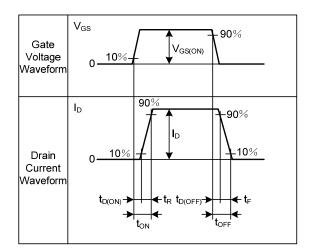
## ■ **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub>=25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltag	е	BV <sub>DSS</sub>	$I_D=250\mu A, V_{GS}=0V$	50			V
Drain-Source Leakage Current		I <sub>DSS</sub>	V <sub>DS</sub> =50V, V <sub>GS</sub> =0V			10	μΑ
Coto Course Leakage Current	Forward	1	V <sub>DS</sub> =0V ,V <sub>GS</sub> =7.0V			5.0	μΑ
Gate-Source Leakage Current	Reverse	I <sub>GSS</sub>	V <sub>DS</sub> =0V ,V <sub>GS</sub> =-7.0V			-5.0	μΑ
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(OFF)}$	$V_{DS}$ =3.0V, $I_{D}$ =1.0 $\mu$ A	0.7	1.0	1.5	V
Drain-Source On-State Resistance		R <sub>DS(ON)1</sub>	$V_{GS}$ =2.5V, $I_D$ =10mA		3	40	Ω
		R <sub>DS(ON)2</sub>	$V_{GS}$ =4.0V, $I_D$ =10mA		2.3	20	Ω
Forward Transconductance		<b>y</b> FS	$V_{DS}$ =3.V, $I_D$ =10mA	20			mS
DYNAMIC PARAMETERS							
Input Capacitance		C <sub>ISS</sub>			27		pF
Output Capacitance		Coss	V <sub>DS</sub> =3.0V, V <sub>GS</sub> =0V, f=1.0MHz		17		pF
Reverse Transfer Capacitance		C <sub>RSS</sub>			11		pF
SWITCHING PARAMETERS							
Turn-ON Delay Time		t <sub>D(ON)</sub>			30		ns
Turn-ON Rise Time		t <sub>R</sub>	$V_{DD}$ =3V, $I_D$ =20mA, $V_{GS(ON)}$ =3V,		18		ns
Turn-OFF Delay Time		t <sub>D(OFF)</sub>	$R_G=10\Omega$ , $R_L=120\Omega$		42		ns
Turn-OFF Fall Time		t <sub>F</sub>			12.5		ns

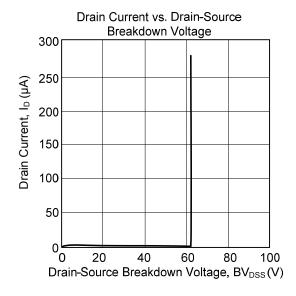
<sup>2.</sup> PW ≤ 10ms, Duty Cycle ≤ 50%

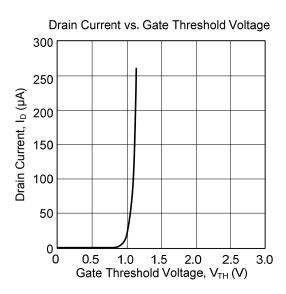
### ■ SWITCHING TIME MEASUREMENT CIRCUIT AND CONDITIONS

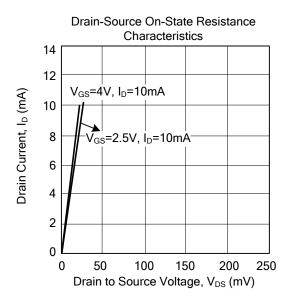


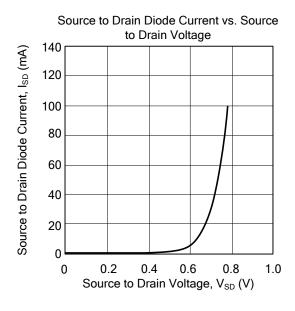


#### **■ TYPICAL CHARACTERISTICS**









UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.